

Schottky Diode

PBYR1045D

45V / 10A

DATASHEET

OEM – Philips

Source: Philips Databook 1999

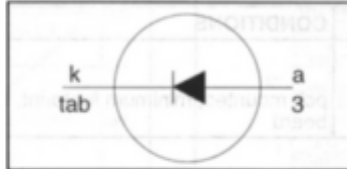
Rectifier diodes Schottky barrier

PBYR1045D series

FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 40 \text{ V} / 45 \text{ V}$$

$$I_{F(AV)} = 10 \text{ A}$$

$$V_F \leq 0.57 \text{ V}$$

GENERAL DESCRIPTION

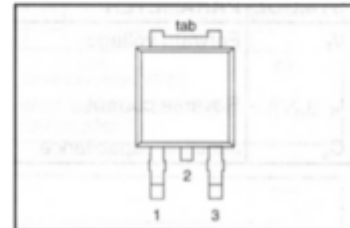
Schottky rectifier diodes in a plastic envelope. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR1045D series is supplied in the surface mounting SOT428 package.

PINNING

PIN	DESCRIPTION
1	no connection
2	cathode ¹
3	anode
tab	cathode

SOT428



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
				PBYR10		
V_{RRM}	Peak repetitive reverse voltage		-	40D 40	45D 45	V
V_{RWM}	Working peak reverse voltage		-	40	45	V
V_R	Continuous reverse voltage	$T_{mb} \leq 113 \text{ }^\circ\text{C}$	-	40	45	V
$I_{F(AV)}$	Average rectified forward current	square wave; $\delta = 0.5$; $T_{mb} \leq 134 \text{ }^\circ\text{C}$	-	10		A
I_{FRM}	Repetitive peak forward current	square wave; $\delta = 0.5$; $T_{mb} \leq 134 \text{ }^\circ\text{C}$	-	20		A
I_{FSM}	Non-repetitive peak forward current	$t = 10 \text{ ms}$	-	100		A
		$t = 8.3 \text{ ms}$	-	110		A
I_{RRM}	Peak repetitive reverse surge current	sinusoidal; $T_j = 125 \text{ }^\circ\text{C}$ prior to surge; with reapplied $V_{RRM(max)}$ pulse width and repetition rate limited by T_{jmax}	-	1		A
T_j	Operating junction temperature		-	150		$^\circ\text{C}$
T_{stg}	Storage temperature		-65	175		$^\circ\text{C}$

¹ It is not possible to make connection to pin 2 of the SOT428 package.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th(j-mb)}$	Thermal resistance junction to mounting base		-	-	2	K/W
$R_{th(j-a)}$	Thermal resistance junction to ambient	pcb mounted, minimum footprint, FR4 board	-	50	-	K/W

ELECTRICAL CHARACTERISTICS

$T_j = 25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 10\text{ A}; T_j = 125^\circ\text{C}$	-	0.5	0.57	V
		$I_F = 20\text{ A}; T_j = 125^\circ\text{C}$	-	0.74	0.8	V
		$I_F = 20\text{ A}$	-	0.65	0.84	V
I_R	Reverse current	$V_R = V_{RWM}$	-	0.2	1.3	mA
		$V_R = V_{RWM}; T_j = 100^\circ\text{C}$	-	22	35	mA
C_d	Junction capacitance	$V_R = 5\text{ V}; f = 1\text{ MHz}; T_j = 25^\circ\text{C to } 125^\circ\text{C}$	-	350	-	pF

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